# <u>Voltage Regulator</u> - Low Dropout, Reset, Sense

# 100 mA, 5.0 V

The NCV4949A is a monolithic integrated 5.0 V voltage regulator with a very low dropout and additional functions such as reset and an uncommitted voltage sense comparator.

It is designed for supplying microcontroller/microprocessor controlled systems particularly in automotive applications. The NCV4949A has improved reset behavior for lower input and output voltage levels.

### Features

- Operating DC Supply Voltage Range 5.0 V to 28 V
- Transient Supply Voltage Up to 40 V
- High Precision Output Voltage 5.0 V ±1%
- Output Current Capability Up to 100 mA
- Very Low Dropout Voltage Less Than 0.4 V
- Reset Circuit Sensing The Output Voltage
- Programmable Reset Pulse Delay
- Voltage Sense Comparator
- Thermal Shutdown and Short Circuit Protections
- AEC-Q100 Grade 1 Qualified and PPAP Capable
- These are Pb-Free Devices

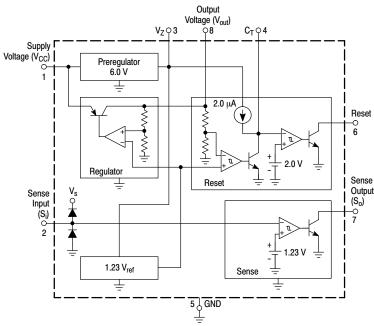
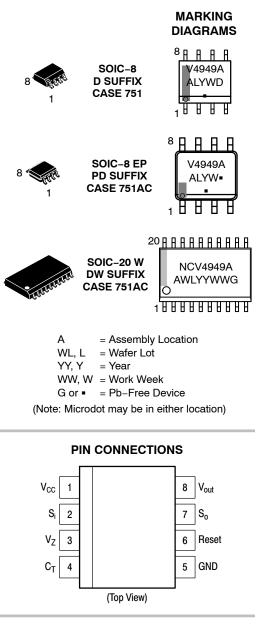


Figure 1. Representative Block Diagram



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#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

#### **ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
DC Operating Supply Voltage (Note 1)	V <sub>CC</sub>	28	V
Transient Supply Voltage (t < 1.0 s) (Note 2)	V <sub>CC TR</sub>	40	V
Output Current	I <sub>out</sub>	Internally Limited	-
Output Voltage (Note 1)	V <sub>out</sub>	20	V
Sense Input Current	۱ <sub>SI</sub>	±1.0	mA
Sense Input Voltage (Note 1)	V <sub>SI</sub>	V <sub>CC</sub>	-
Output Voltages (Note 1)			V
Reset Output	V <sub>Reset</sub>	20	
Sense Output	V <sub>SO</sub>	20	
Output Currents			mA
Reset Output	I <sub>Reset</sub>	5.0	
Sense Output	I <sub>SO</sub>	5.0	
Preregulator Output Voltage (Note 1)	VZ	7.0	V
Preregulator Output Current	Ι <sub>Ζ</sub>	5.0	mA
Reset Delay Voltage (Note 1)	CT	7.0	V
Reset Delay Current	CT	Internally Limited	-
ESD Protection at any pin			V
Human Body Model	-	4000	
Machine Model	-	200	
Charged Device Model (SOIC-20 W)	-	1000	
Thermal Resistance, Junction-to-Air	R <sub>θJA</sub>		°C/W
SOIC–8 SOIC–8 EP SOIC–20 W		189.3 84.8 95.8	
Operating Junction Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Absolute negative voltage on these pins not to go below –0.3 V.

2. Load Dump Test B (with centralized load dump suppression) according to ISO16750-2 standard. Guaranteed by design. Not tested in production. Passed Class B (Vout < 5.5 V) according to ISO16750-1.

#### LEAD TEMPERATURE SOLDERING REFLOW (Note 3)

Rating	Symbol	Min	Мах	Unit
Reflow (SMD styles only) lead free 60 - 150 sec above 217, 40 sec max at peak	Tsld	-	260	°C
Moisture Sensitivity Level (SOIC-8)	MSL	Lev	el 1	
Moisture Sensitivity Level (SOIC-8EP)	MSL	Lev	el 2	
Moisture Sensitivity Level (SOIC-20W)	MSL	Lev	el 3	

3. Per IPC / JEDEC J-STD-020C

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (T <sub>A</sub> = 25°C, I <sub>out</sub> = 1.0 mA)	V <sub>out</sub>	4.95	5.0	5.05	V
Output Voltage (6.0 V < V <sub>CC</sub> < 28 V, 1.0 mA < $I_{out}$ < 50 mA)	V <sub>out</sub>	4.9	5.0	5.1	V
Output Voltage (V <sub>CC</sub> = 35 V, t < 1.0 s, 1.0 mA < I <sub>out</sub> < 50 mA)	V <sub>out</sub>	4.9	5.0	5.1	V
Dropout Voltage	V <sub>drop</sub>				V
l <sub>out</sub> = 10 mA		_	0.1	0.25	
l <sub>out</sub> = 50 mA		_	0.2	0.40	
l <sub>out</sub> = 100 mA		-	0.3	0.50	
Input to Output Voltage Difference in Undervoltage Condition	V <sub>IO</sub>	-	0.2	0.4	V
(V <sub>CC</sub> = 4.0 V, I <sub>out</sub> = 35 mA)					
Line Regulation (6.0 V < V <sub>CC</sub> < 28 V, I <sub>out</sub> = 1.0 mA)	Reg <sub>line</sub>	-	1.0	20	mV
Load Regulation (1.0 mA < I <sub>out</sub> < 100 mA)	Reg <sub>load</sub>	_	8.0	30	mV
Current Limit	I <sub>Lim</sub>				mA
$V_{out} = 4.5 V$		105	200	400	
V <sub>out</sub> = 0 V		-	100	-	
Quiescent Current (I <sub>out</sub> = 0.3 mA, T <sub>A</sub> < 100°C)	I <sub>QSE</sub>	-	150	260	μA
Quiescent Current (I <sub>out</sub> = 100 mA)	Ι <sub>Q</sub>	-	_	5.0	mA
RESET		1 1			
Reset Threshold Voltage	V <sub>Resth</sub>	-	4.5	-	V
Reset Threshold Hysteresis	V <sub>Resth,hys</sub>				mV
@ T <sub>A</sub> = 25°C		50	100	200	
@ T <sub>A</sub> = -40 to +125°C		50	-	300	
Reset Pulse Delay (C <sub>T</sub> = 100 nF, $t_R \ge 100 \ \mu s$ )	t <sub>ResD</sub>	55	100	180	ms
Reset Reaction Time (C <sub>T</sub> = 100 nF)	t <sub>ResR</sub>	_	5.0	30	μs
Reset Output Low Voltage (R <sub>Reset</sub> = 10 k $\Omega$ to V <sub>out</sub> , V <sub>CC</sub> $\ge$ 3.0 V)	V <sub>ResL</sub>	-	-	0.4	V
Reset Output High Leakage Current (V <sub>Reset</sub> = 5.0 V)	I <sub>ResH</sub>	-	-	1.0	μA
Delay Comparator Threshold	V <sub>CTth</sub>	-	2.0	_	V
Delay Comparator Threshold Hysteresis	V <sub>CTth, hys</sub>	-	100	_	mV
SENSE		1 1			
Sense Low Threshold (V <sub>SI</sub> Decreasing = 1.5 V to 1.0 V)	V <sub>SOth</sub>	1.16	1.23	1.35	V
Sense Threshold Hysteresis	V <sub>SOth,hys</sub>	20	100	200	mV
Sense Output Low Voltage (V <sub>SI</sub> $\leq$ 1.16 V, V <sub>CC</sub> $\geq$ 3.0 V, R <sub>SO</sub> = 10 k $\Omega$ to V <sub>out</sub> )	V <sub>SOL</sub>	_	_	0.4	V
Sense Output Leakage (V <sub>SO</sub> = 5.0 V, V <sub>SI</sub> $\ge$ 1.5 V)	I <sub>SOH</sub>	-	_	1.0	μA
Sense Input Current	I <sub>SI</sub>	-1.0	0.1	1.0	μA
PREREGULATOR	L	<u> </u>		_	
Preregulator Output Voltage ( $I_Z = 10 \mu A$ )	Vz		6.3		V

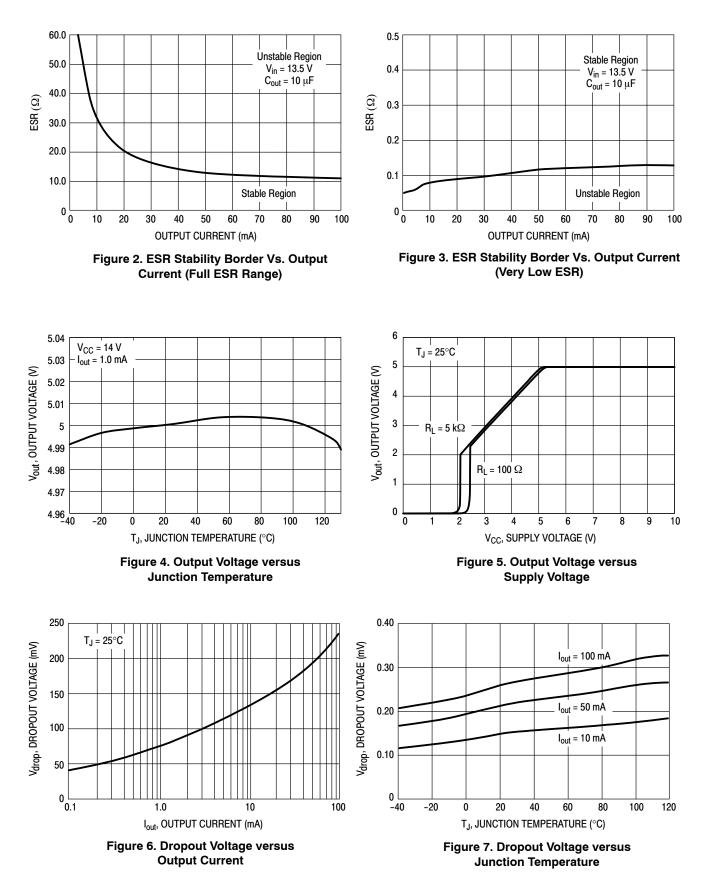
ELECTRICAL CHARACTERISTICS	$(V_{CC} = 14 \text{ V}, -40^{\circ}\text{C} < T_{A} < 125^{\circ}\text{C}, \text{ unless otherwise specified.})$
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

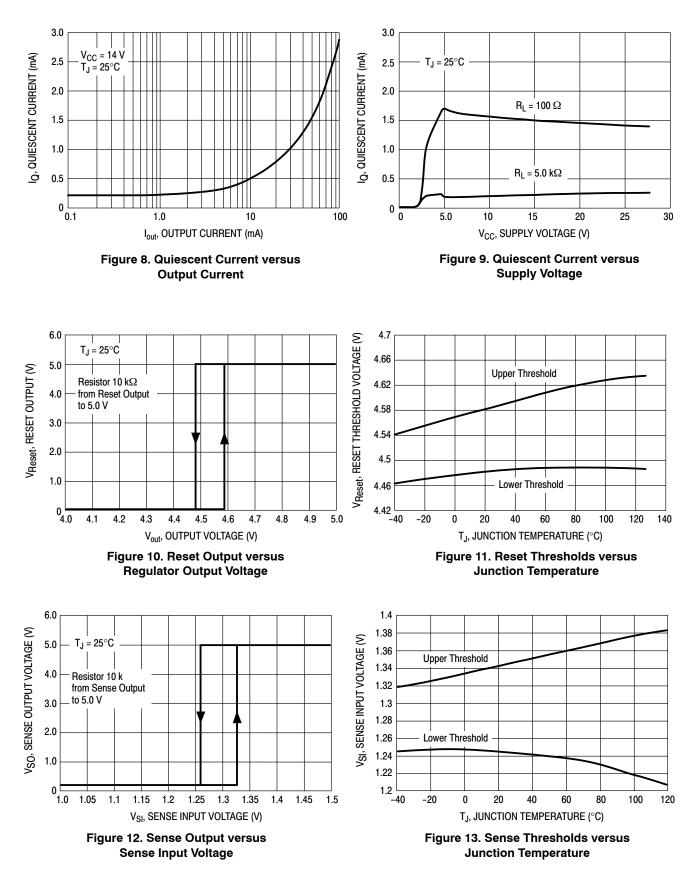
### **PIN FUNCTION DESCRIPTION**

Pin SO-8, SO-8 EP	Pin SO–20 W	Symbol	Description
1	19	V <sub>CC</sub>	Supply Voltage
2	20	SI	Input of Sense Comparator. If not used, connect to Vout.
3	1	VZ	Output of Preregulator
4	2	C <sub>T</sub>	Reset Delay Capacitor
5	4–7, 14–17	GND	Ground
6	10	Reset	Output of Reset Comparator
7	11	S <sub>O</sub>	Output of Sense Comparator
8	12	V <sub>out</sub>	Main Regulator Output
-	3, 8, 9, 13, 18	NC	No Connect

# **TYPICAL CHARACTERIZATION CURVES**



## TYPICAL CHARACTERIZATION CURVES (continued)

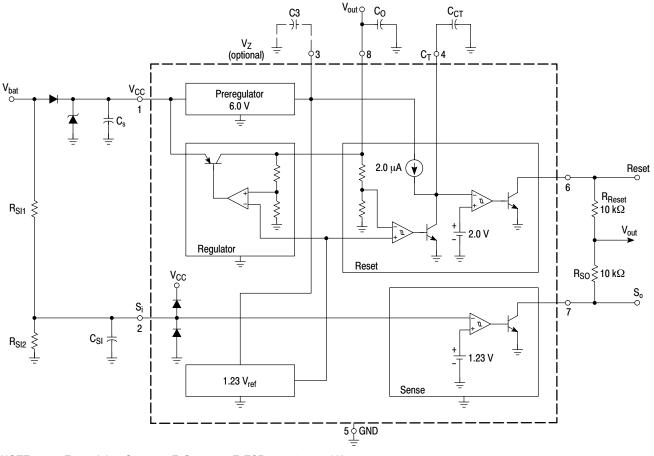


## **APPLICATION INFORMATION**

#### **Supply Voltage Transient**

High supply voltage transients can cause a reset output signal perturbation. For supply voltages greater than 8.0 V the circuit shows a high immunity of the reset output against supply transients of more than 100 V/ $\mu$ s. For supply voltages

less than 8.0 V supply transients of more than 0.4 V/µs can cause a reset signal perturbation. To improve the transient behavior for supply voltages less than 8.0 V a capacitor at Pin 3 can be used. A capacitor at Pin 3 (C3  $\leq$  1.0 µF) also reduces the output noise.



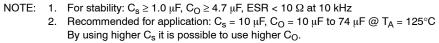


Figure 14. Application Schematic

#### **OPERATING DESCRIPTION**

The NCV4949A is a monolithic integrated low dropout voltage regulator. Several outstanding features and auxiliary functions are implemented to meet the requirements of supplying microprocessor systems in automotive applications. It is also suitable in other applications where the included functions are required. The modular approach of this device allows the use of other features and functions independently when required.

#### **Voltage Regulator**

The voltage regulator uses an isolated collector vertical PNP transistor as a regulating element. With this structure, very low dropout voltage at currents up to 100 mA is obtained. The dropout operation of the standby regulator is maintained down to 3.0 V input supply voltage. The output voltage is regulated up to a transient input supply voltage of 35 V.

A typical curve showing the standby output voltage as a function of the input supply voltage is shown in Figure 16.

The current consumption of the device (quiescent current) is less than 200  $\mu$ A.

To reduce the quiescent current peak in the undervoltage region and to improve the transient response in this region, the dropout voltage is controlled. The quiescent current as a function of the supply input voltage is shown in Figure 17.

#### Short Circuit Protection:

The maximum output current is internally limited. In case of short circuit, the output current is foldback current limited as described in Figure 15.

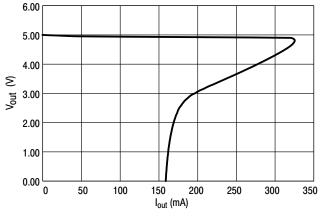


Figure 15. Foldback Characteristic of Vout

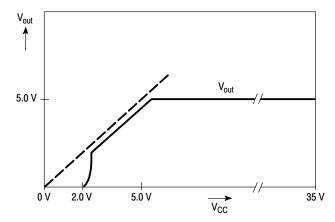


Figure 16. Output Voltage versus Supply Voltage

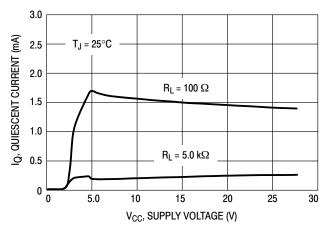


Figure 17. Quiescent Current versus Supply Voltage

#### Preregulator

To improve transient immunity a preregulator stabilizes the internal supply voltage to 6.0 V. This internal voltage is present at Pin 3 (V<sub>Z</sub>). This voltage should not be used as an output because the output capability is very small ( $\leq$  100 µA).

This output may be used to improve transient behavior for supply voltages less than 8.0 V. In this case a capacitor (100 nF –  $1.0 \,\mu$ F) must be connected between Pin 3 and GND. If this feature is not used Pin 3 must be left open.

### **Reset Circuit**

The block circuit diagram of the reset circuit is shown in Figure 18.

The reset circuit supervises the output voltage. The reset threshold of 4.5 V is defined by the internal reference voltage and standby output divider.

The reset pulse delay time  $t_{RD}$ , is defined by the charge time of an external capacitor  $C_T$ :

$$t_{\rm RD} = \frac{C_{\rm T} \times 2.0 \,\rm V}{2.0 \,\mu\rm A}$$

The reaction time of the reset circuit originates from the discharge time limitation of the reset capacitor  $C_T$  and is proportional to the value of  $C_T$ . The reaction time of the reset circuit increases the noise immunity.

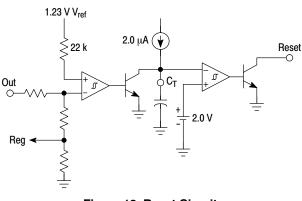


Figure 18. Reset Circuit

**ORDERING INFORMATION** 

Output voltage drops below the reset threshold only marginally longer than the reaction time results in a shorter reset delay time.

The nominal reset delay time will be generated for output voltage drops longer than approximately 50  $\mu$ s. The typical reset output waveforms are shown in Figure 19.

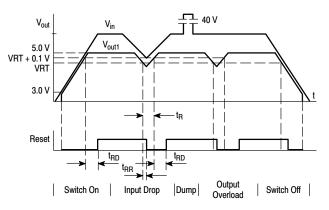


Figure 19. Typical Reset Output Waveforms

#### Sense Comparator

The sense comparator compares an input signal with an internal voltage reference of typical 1.23 V. The use of an external voltage divider makes this comparator very flexible in the application.

It can be used to supervise the input voltage either before or after a protection diode and to provide additional information to the microprocessor such as low voltage warnings.

Device	Package	Shipping <sup>†</sup>
NCV4949ADR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV4949APDR2G	SOIC-8 EP (Pb-Free)	2500 / Tape & Reel
NCV4949ADWR2G	SOIC-20 WB (Pb-Free)	1000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications,including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### SOIC-8 NB CASE 751-07 ISSUE AK

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. 4. DRAIN, #2 GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. LINE 1 OUT 8. STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. SOURCE SOURCE 6. SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE, #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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SOURCE 1/DRAIN 2

7.

8. GATE 1

COLLECTOR, #2

COLLECTOR, #1

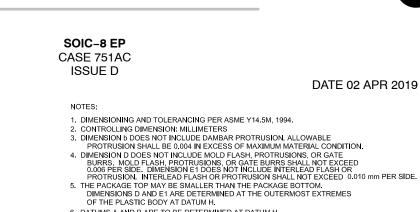
COLLECTOR, #1

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7.

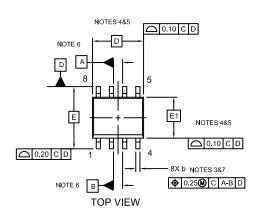
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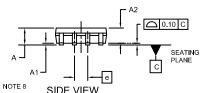
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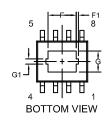


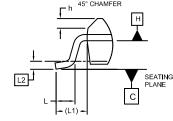
6. DATUMS A AND B ARE TO BE DETERMINED AT DATUM H.

DIMENSIONS 5 AND C APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 TO 0.25 FROM THE LEAD TIP.
A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.



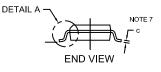


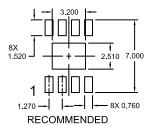




45° CHAMFER

DETAIL A





	MILLIMETERS			
DIM	MIN.	NOM	MAX.	
А	1.35	1.55	1.75	
A1		0.05	0.10	
A2	1.35	1.50	1.65	
b	0.31	0.41	0.51	
с	0.17	0.21	0.23	
D		4.90 BSC		
Е	6.00 BSC			
E1	3.90 BSC			
е	1.27 BSC			
F	2.24	2.72	3.20	
F1	0.15	0.20	0.25	
G	1.55	2.03	2.51	
G1	0.41	0.46	0.51	
h	0.25	0.38	0.50	
L	0.40	0.84	1.27	
L1	1.04 REF			
L2	0.25 REF			
Ø	0°	4°	8°	

**MOUNTING FOOTPRINT\*** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D."

### GENERIC **MARKING DIAGRAM\***

<sup>B</sup> E		
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XXXXX	= Specific Device Code
4	= Assembly Location
Y	= Year
NW	= Work Week
	= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " -", may or may not be present and may be in either location. Some products may not follow the Generic Marking.

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